

# Spread Spectrum Clock Generator

## **Description**

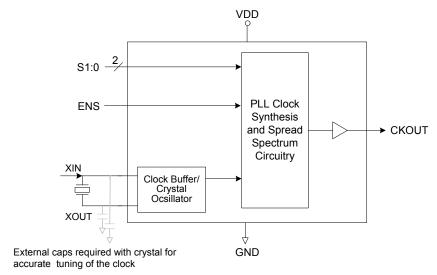
The ICS7151-10, -20, -40, and -50 are clock generators for EMI (Electro Magnetic Interference) reduction (see below for frequency ranges and multiplier ratios). Spectral peaks can be attenuated by making the oscillation frequency modulate slightly. Both down and center spread profiles are selectable. Down spread maintains an average frequency equal to an unspread clock, and down spread meets maximum frequency specs over the entire modulation cycle.

ICS offers many other clocks for computers and computer peripherals. Consult ICS when you need to remove crystals and oscillators from your board.

### **Features**

- Operating voltage of 3.3 V ±0.3 V
- Packaged in 8-pin SOIC
- · Available in Pb (lead) free package
- Input frequency range of 16.6 to 33.4 MHz
- Output frequency ranges of 8.3 to 16.7 MHz, 16.6 to 33.4 MHz, 33.3 to 66.7 MHz, 66.6 to 133.4 MHz
- Provides a spread spectrum clock output (±0.5%, ±1.5% center spread; -1.0%, -3.0% down spread)
- Input oscillation circuit: range of 16.6 to 33.4 MHz
- Multiplication rates of x1/2, x1, x2, and x4
- Advanced, low-power CMOS process

## **Block Diagram**

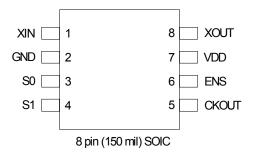


# **Product Lineup**

Product	Input Frequency Range	Multiplier Ratio	Output Frequency Range
ICS7151M-10, ICS7251MI-10	16.6 MHz to 33.4 MHz	X1	16.6 MHz to 33.4 MHz
ICS7151M-20, ICS7151MI-20	16.6 MHz to 33.4 MHz	X2	33.3 MHz to 66.7 MHz
ICS7151M-40, ICS7151MI-40	16.6 MHz to 33.4 MHz	X4	66.6 MHz to 133.4 MHz
ICS7151M-50, ICS7151MI-50	16.6 MHz to 33.4 MHz	X1/2	8.3 MHz to 16.7 MHz



# **Pin Assignment**



# **Spread Direction and Percentage Select Table**

S1 Pin 4 (note1)	S0 Pin 3 (note1)	Spread Direction	Spread Percentage (%)	
0	0	Center	±1.5	
0	1	Center	±0.5	
1	0	Down	-1.0	
1	1	Down	-3.0	
_	NS te 2)	Modulation		
	0	No Modulation		
	1	Modulation		

#### Notes:

- 1. The modulation rate can be changes at the level of the terminal.
- 2. Spectrum does not spread when "0" is set to ENS (unmodulated clock). Because it has a pull-up resistor, spread spectrum when is enabled when ENS is high or open.

# **Pin Descriptions**

Pin Number	Pin Name	Pin Type	Pin Description
1	XIN	Input	Resonator connection pin/clock input pin.
2	GND	Power	Connect to ground.
3	S0	Input	Select pin 0. Modulation rate setting pin.
4	S1	Input	Select pin 1. Modulation rate setting pin.
5	CKOUT	Output	Modulated clock output pin.
6	ENS	Input	Modulation enable setting pin. Internal pull-up resistor.
7	VDD	Power	Connect to +3.3 V.
8	XOUT	Output	Resonator connection pin.



## **External Components**

The ICS7151 requires a minimum number of external components for proper operation.

#### **Decoupling Capacitor**

A decoupling capacitor of 0.01µF must be connected between GND and VDD on pins 2 and 7, as close to these pins as possible. For optimum device performance, the decoupling capacitor should be mounted on the component side of the PCB. Avoid the use of vias in the decoupling circuit.

#### **Series Termination Resistor**

Series termination should be used on the clock output. To series terminate a  $50\Omega$  trace (a commonly used trace impedance) place a  $5\Omega$  resistor in series with the clock line, as close to the clock output pin as possible. The nominal impedance of the clock output is  $45\Omega$ .

### **PCB Layout Recommendations**

For optimum device performance and lowest output phase noise, the following guidelines should be observed.

- 1) The  $0.01\mu F$  decoupling capacitor should be mounted on the component side of the board as close to the VDD pin as possible. No vias should be used between the decoupling capacitor and VDD pin. The PCB trace to VDD pin should be kept as short as possible, as should the PCB trace to the ground via.
- 2) To minimize EMI, the  $5\Omega$  series termination resistor (if needed) should be placed close to the clock output.
- 3) An optimum layout is one with all components on the same side of the board, minimizing vias through other signal layers. Other signal traces should be routed away from the ICS7151. This includes signal traces just

underneath the device, or on layers adjacent to the ground plane layer used by the device.

#### **Crystal Information**

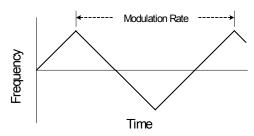
The crystal used should be a fundamental mode (do not use third overtone), parallel resonant. Crystal capacitors should be connected from pins X1 to ground and X2 to ground to optimize the initial accuracy. The value of these capacitors is given by the following equation:

Crystal caps (pF) = 
$$(C_L - 6) \times 2$$

In the equation,  $C_L$  is the crystal load capacitance. So, for a crystal with a 16 pF load capacitance, two 20 pF [(16-6) x 2] capacitors should be used.

## Spread Spectrum Profile

The ICS7151 low EMI clock generator uses a triangular frequency modulation profile for optimal down stream tracking of zero delay buffers and other PLL devices. The frequency modulation amplitude is constant with variations of the input frequency.



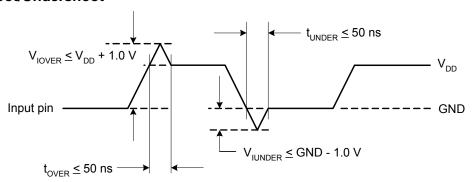


# **Absolute Maximum Ratings**

Stresses above the ratings listed below can cause permanent damage to the ICS7151. These ratings, which are standard values for ICS commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

Item	Rating
Supply Voltage, VDD	-0.5 to 4.0 V
All Inputs and Outputs (referenced to GND)	-0.5 V to VDD+0.5 V
Ambient Operating Temperature	-40 to +85°C
Storage Temperature	-55 to +125°C
Junction Temperature	-40 to +125°C
Soldering Temperature	260°C
Overshoot (V <sub>IOVER</sub> )	VDD + 1.0 V (t <sub>OVER</sub> ≤ 50 ns)
Undershoot (V <sub>IUNDER</sub> )	GND - 1.0 V (t <sub>UNDER</sub> ≤ 50 ns)

#### Overshoot/Undershoot



# **Recommended Operation Conditions**

Parameter	Min.	Тур.	Max.	Units
Ambient Operating Temperature	-40		+85	°C
Power Supply Voltage (measured in respect to GND)	+3.0	3.3	3.6	V



## **DC Electrical Characteristics**

Unless stated otherwise, VDD = 3.3 V ±0.3 V, Ambient Temperature -40 to +85°C

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Operating Voltage	VDD		3.0	3.3	3.6	V
Supply Current	IDD	No load, at 3.3 V, output = 24 MHz		10	14	mA
Input Frequency			16.6		33.4	MHz
Input High Voltage	V <sub>IH</sub>	XIN, S0, S1, ENS	VDD * 0.8		VDD + 0.3	V
Input Low Voltage	V <sub>IL</sub>	XIN, S0, S1, ENS	0.0		VDD * 0.20	V
Output High Voltage	V <sub>OH</sub>	CKOUT, I <sub>OH</sub> = -4 mA	2.0			V
Output Low Voltage	V <sub>OL</sub>	CKOUT, I <sub>OL</sub> = 4 mA			0.4	V
Input Capacitance	C <sub>IN</sub>	XIN, S0, S1, ENS			16	pF
		CKOUT, 8.3 to 66.7 MHz			15	pF
Load Capacitance	C <sub>L</sub>	CKOUT, 66.7 to 100 MHz			10	pF
		CKOUT, 100 to 133.4 MHz			7	pF
Input Pull-up Resistor	R <sub>PU</sub>	ENS	100	240	400	kΩ

## **AC Electrical Characteristics**

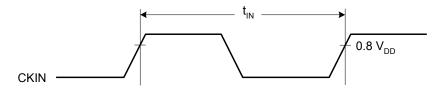
Unless stated otherwise, VDD = 3.3 V ±0.3 V, Ambient Temperature -40 to +85° C

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Oscillation frequency	f <sub>X</sub>	Fundamental oscillation	16.6		33.4	MHz
Input Frequency	f <sub>IN</sub>	XIN	16.6		33.4	MHz
Output Frequency		CKOUT, Multiply by 1 (ICS7151-10)	16.6		33.4	MHz
	f <sub>ОИТ</sub>	CKOUT, Multiply by 2 (ICS7151-20)	33.3		66.7	MHz
		CKOUT, Multiply by 4 (ICS7151-40)	66.6		133.4	MHz
		CKOUT, 2-frequency division (ICS7151-50)	8.3		16.7	MHz
Input Clock Duty Cycle		XIN, 16.6 to 33.4 MHz	40	50	60	%
Output Clock Duty Cycle	t <sub>DCC</sub>	CKOUT, 1.5 V	40		60	%
Output Slew Rate		CKOUT, 0.4 to 2.4 V, load capacitance 15 pF	0.5		3.0	V/ns

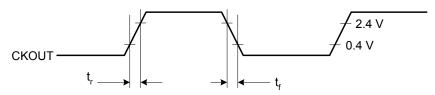


Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
		No load, standard deviation (ICS7151-10, -20)			100	ps
Cycle to Cycle Jitter	t <sub>JC</sub>	No load, standard deviation (ICS7151-40)			150	ps
		No load, standard deviation (ICS7151-50)			200	ps
Lock-up Time	t <sub>LK</sub>	CKOUT,		2	5	ms
Modulation Frequency	f <sub>MOD</sub>	CKOUT,		33		kHz

# Input Frequency $(f_{IN} = 1/t_{IN})$



## **Output Slew Rate**



 $SR = (2.4 - 0.4) / t_r$ ,  $SR = (2.4 - 0.4) / t_f$ 

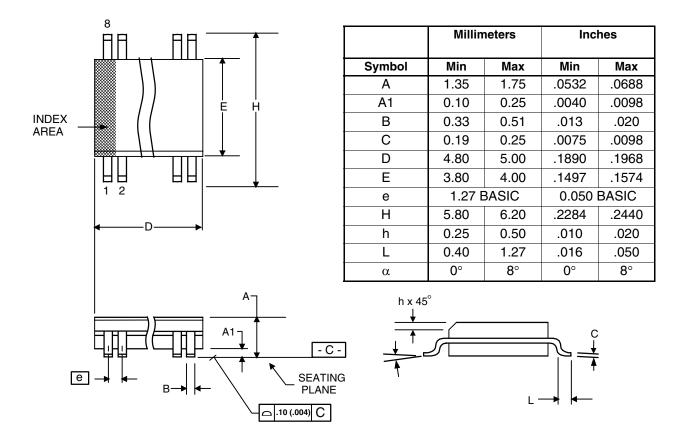
# **Thermal Characteristics 8 SOIC**

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Thermal Resistance Junction to	$\theta_{\sf JA}$	Still air		150		°C/W
Ambient	$\theta_{\sf JA}$	1 m/s air flow		140		°C/W
	$\theta_{\sf JA}$	3 m/s air flow		120		°C/W
Thermal Resistance Junction to Case	$\theta_{\sf JC}$			40		°C/W



# Package Outline and Package Dimensions (8-pin SOIC, 150 Mil. Body)

Package dimensions are kept current with JEDEC Publication No. 95





## **Ordering Information**

Part / Order Number	Marking	<b>Shipping Packaging</b>	Package	Temperature
ICS7151M-10	7151M-10	Tubes	8-pin SOIC	0 to +70° C
ICS7151M-10T	7151M-10	Tape and Reel	8-pin SOIC	0 to +70° C
ICS7151M-10LF	7151M10L	Tubes	8-pin SOIC	0 to +70° C
ICS7151M-10LFT	7151M10L	Tape and Reel	8-pin SOIC	0 to +70° C
ICS7151M-20	7151M-20	Tubes	8-pin SOIC	0 to +70° C
ICS7151M-20T	7151M-20	Tape and Reel	8-pin SOIC	0 to +70° C
ICS7151M-20LF	7151M20L	Tubes	8-pin SOIC	0 to +70° C
ICS7151M-20LFT	7151M20L	Tape and Reel	8-pin SOIC	0 to +70° C
ICS7151M-40	7151M-40	Tubes	8-pin SOIC	0 to +70° C
ICS7151M-40T	7151M-40	Tape and Reel	8-pin SOIC	0 to +70° C
ICS7151M-40LF	7151M40L	Tubes	8-pin SOIC	0 to +70° C
ICS7151M-40LFT	7151M40L	Tape and Reel	8-pin SOIC	0 to +70° C
ICS7151M-50	7151M-50	Tubes	8-pin SOIC	0 to +70° C
ICS7151M-50T	7151M-50	Tape and Reel	8-pin SOIC	0 to +70° C
ICS7151M-50LF	7151M50L	Tubes	8-pin SOIC	0 to +70° C
ICS7151M-50LFT	7151M50L	Tape and Reel	8-pin SOIC	0 to +70° C
ICS7151MI-10	7151MI10	Tubes	8-pin SOIC	-40 to +85° C
ICS7151MI-10T	7151MI10	Tape and Reel	8-pin SOIC	-40 to +85° C
ICS7151MI-10LF	51MI10LF	Tubes	8-pin SOIC	-40 to +85° C
ICS7151MI-10LFT	51MI10LF	Tape and Reel	8-pin SOIC	-40 to +85° C
ICS7151MI-20	7151MI20	Tubes	8-pin SOIC	-40 to +85° C
ICS7151MI-20T	7151MI20	Tape and Reel	8-pin SOIC	-40 to +85° C
ICS7151MI-20LF	51MI20LF	Tubes	8-pin SOIC	-40 to +85° C
ICS7151MI-20LFT	51MI20LF	Tape and Reel	8-pin SOIC	-40 to +85° C
ICS7151MI-40	7151MI40	Tubes	8-pin SOIC	-40 to +85° C
ICS7151MI-40T	7151MI40	Tape and Reel	8-pin SOIC	-40 to +85° C
ICS7151MI-40LF	51MI40LF	Tubes	8-pin SOIC	-40 to +85° C
ICS7151MI-40LFT	51MI40LF	Tape and Reel	8-pin SOIC	-40 to +85° C
ICS7151MI-50	7151MI50	Tubes	8-pin SOIC	-40 to +85° C
ICS7151MI-50T	7151MI50	Tape and Reel	8-pin SOIC	-40 to +85° C
ICS7151MI-50LF	51MI50LF	Tubes	8-pin SOIC	-40 to +85° C
ICS7151MI-50LFT	51MI50LF	Tape and Reel	8-pin SOIC	-40 to +85° C

#### Parts that are ordered with a "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

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